

Electronic supplementary material Table 1: Fit parameters of the zinc EAM potential. The parameters of Eq. 10 can be calculated from $F'(\rho_e)$ and $F''(\rho_e)$ with the equations given below derived here to implement the constraints of the embedding function.

<i>parameter</i>	<i>value</i>
$f_e / 10^{-18} \text{ C nm}^{-3}$	0.56638674
β	5.75486
$Z_e / 10^{-18} \text{ C}$	0.021945331
α	4.2369
$F(\rho_e) / \text{eV}$	-1.73505924326
$F'(\rho_e) / \text{eV nm}^3 \text{ C}^{-1}$	$-2.248592 \cdot 10^{17}$
$F''(\rho_e) / \text{eV nm}^6 \text{ C}^{-2}$	$5.0047652 \cdot 10^{31}$
$F_{b3} / \text{eV nm}^9 \text{ C}^{-3}$	$1.3050788 \cdot 10^{51}$
r_e / nm	0.2665
$\rho_e / 10^{-18} \text{ C nm}^{-3}$	5.7382624
$\rho_{\max} / 10^{-18} \text{ C nm}^{-3}$	21.083445

$$F_{a0} = \frac{F(\rho_e)}{\rho_e} \quad F_{a1} = \frac{F'(\rho_e)\rho_e - F(\rho_e)}{\rho_e^2}$$

$$F_{a2} = \frac{F''(\rho_e)\rho_e^2 - 2F'(\rho_e)\rho_e + 2F(\rho_e)}{3\rho_e^2}$$

$$F_{b0} = F(\rho_e)$$

$$F_{b1} = F'(\rho_e)$$

$$F_{b2} = 0.5 F''(\rho_e)$$

Electronic supplementary material Table 2: CNA signatures for the hcp structure. The letters A and B indicate to which layer of the plane the atom belongs, in case the surface consists of two planes. Existing structures with the same signature are listed too.

<i>Structure</i>	#nn	CNA(#),...
Bulk	12	422(6), 421(6)
(0001) A/B- layer \equiv fcc (111) <i>plane</i>	9	421(3), 311(6)
(1010) A-layer \equiv <i>icosahedron surface edge</i>	8	422(2), 322(2), 311(4)
(1010) B- layer \equiv <i>decahedron bulk</i>	10	422(2), 421(2), 311(4), 300(2)
(1100) A- layer	6	422(2), 211(2), 100(2)
(1100) B- layer	10	422(2), 421(4), 322(2), 211(2)
(1011) A- layer \equiv (1101) B \equiv (1102) B	9	422(2), 421(2), 322(2), 311(2), 211(1)
(1101) A- layer \equiv (1011) B \equiv (1012) B	8	422(2), 421(1), 311(2), 211(1), 200(2)
(1012) A- layer \equiv fcc (111)-(100) <i>edge</i>	7	421(2), 311(2), 211(3)
(1102) A- layer \equiv fcc (111)-(111) <i>edge</i>	7	421(1), 311(4), 200(2)
(1120) A/B- layer \equiv <i>decahedron notch vertex</i>	7	422(1), 322(1), 311(2), 300(1), 200(2)
(1121) A/B- layer	7	422(1), 421(1), 322(1), 311(1), 211(2), 200(1)
(112 $\frac{1}{2}$) A- layer	6	422(1), 322(1), 311(1), 211(1), 200(2)
(0001)-(1010)-edge \equiv <i>tetrahedron edge</i>	6	311(4), 211(2)
(0001)-(1100)-edge	5	311(2), 211(1), 100(2)
(0001)-(1010)-(1100) -vertex \equiv <i>octahedron vertex</i>	6	421(1), 311(2), 211(2), 200(1)